



TND525SS

Excellent Power Device Half-bridge Drive, Single SOIC8

ON Semiconductor®

<http://onsemi.com>

Features

- 2-input 2-output half-bridge drive
- Low side output supervisory circuit is built in (Simultaneous ON preventing circuit)
- Allows simplified configuration of driver circuit
- Withstand voltage of 600V is assured
- High-speed switching
- Monolithic structure
- Fully compatible input to LSTTL/CMOS
- Output current: 170mA Source, 340mA Sink
- Halogen free compliance

Specifications

Absolute Maximum Ratings at Ta=25°C (All voltage parameters are absolute voltage referenced to GND)

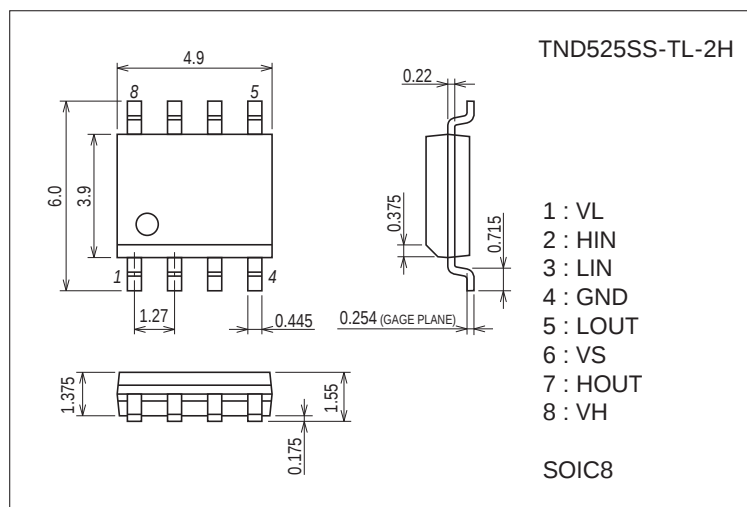
Parameter	Symbol	Conditions	Ratings	Unit
High Side Floating Supply Voltage	V _H		-0.3 to 625	V
High Side Floating Supply Offset Voltage	V _S		V _H -25 to V _H +0.3	V
High Side Output Voltage	V _{HOUT}		V _S -0.3 to V _H +0.3	V
Low Side Supply Voltage	V _L		-0.3 to 25	V
Low Side Output Voltage	V _{LOUT}		-0.3 to V _L +0.3	V
Logic Input Voltage (H _{IN} , L _{IN})	V _{IN}		-0.3 to V _L +0.3	V
The Maximum Allowable Offset Voltage Supply dv/dt	dV _S /dt		50	V/ns
Allowable Power Dissipation	P _D	When mounted on ceramic substrate (1200mm ² ×0.8mm)	1.2	W
Junction Temperature	T _j		-55 to +150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

unit : mm (typ)

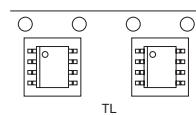
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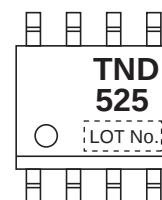
Product & Package Information

- Package : SIOC8
- JEITA, JEDEC : SC-87, SOT-96
- Minimum Packing Quantity : 2,500 pcs./reel

Packing Type: TL



Marking



TND525SS

Recommend Operating Conditions at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
High Side Floating Supply Voltage	V _H		V _S +10 to V _S +20	V
High Side Floating Supply Offset Voltage	V _S	V _L =V _{HS} =15V	-5 to 600	V
High Side Output Voltage	V _{HOUT}		V _S to V _H	V
Low Side Supply Voltage	V _L		+10 to +20	V
Low Side Output Voltage	V _{LOUT}		0 to V _L	V
Logic Input Voltage (H _{IN} , L _{IN})	V _{IN}		0 to V _L	V
Ambient Temperature	Topr		-40 to +125	°C

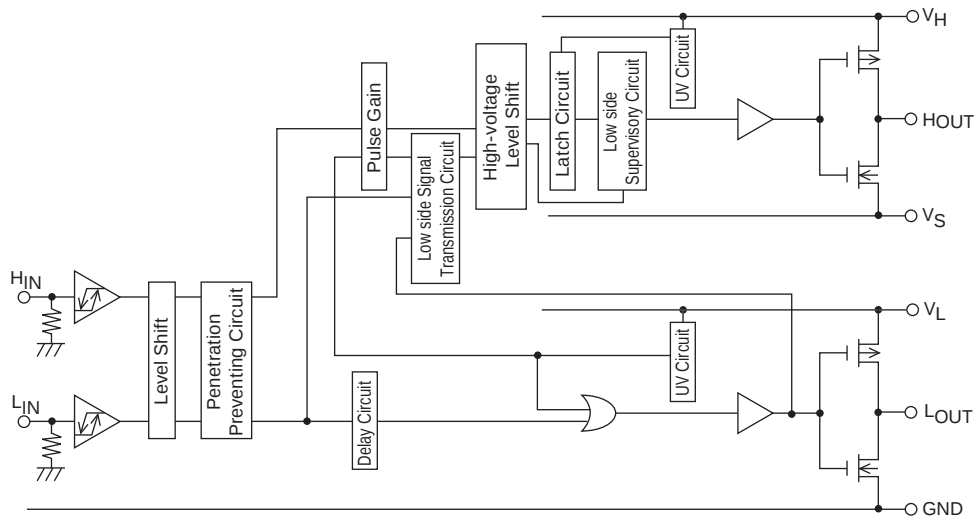
AC Characteristics at Ta=25°C (V_L=V_{HS}=15V, C_L=1000pF)

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Turn-ON Delay Time	t _{on}	V _S =0V	70	100	130	ns
Turn-OFF Delay Time	t _{off}	V _S =0V	60	90	120	ns
Turn-ON Rise Time	t _r			80	110	ns
Turn-OFF Fall Time	t _f			35	55	ns
Delay Matching, HS and LS Turn-ON	Mt _{on}	Ht _{on} - Lt _{on}		5	30	ns
Delay Matching, HS and LS Turn-OFF	Mt _{off}	Ht _{off} - Lt _{off}		5	30	ns

DC Characteristics at Ta=25°C (V_L=V_{HS}=15V)

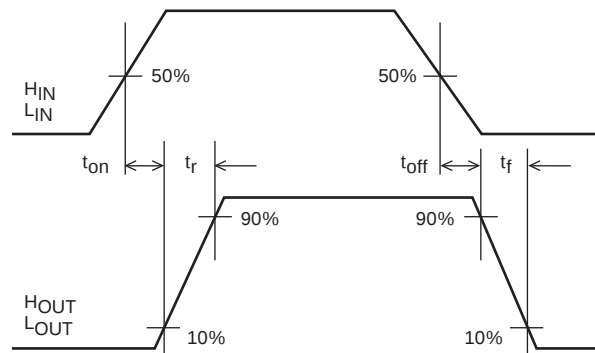
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Logic "1" Input Voltage	V _{IH}	V _L =10 to 20V	2.8			V
Logic "0" Input Voltage	V _{IL}	V _L =10 to 20V			0.8	V
High-level Output Voltage, V _{BIAS} -V _O	V _{OH}	V _{IN} =V _{IH} , I _O =0A			0.1	V
Low-level Output Voltage, V _O	V _{OL}	V _{IN} =V _{IL} , I _O =0A			0.1	V
Offset Supply Leakage Current	I _{LK}	V _H =V _S =600V			10	μA
Quiescent V _H Supply Current	I _{QH}	V _{IN} =0V		50	100	μA
		V _{IN} =V _L		60	100	μA
Quiescent V _L Supply Current	I _{QL}	V _{IN} =0V		130	230	μA
		V _{IN} =V _L		170	260	μA
Logic "1" Input Bias Current	I _{IN+}	V _{IN} =V _L		20	55	μA
Logic "0" Input Bias Current	I _{IN-}	V _{IN} =0V			1	μA
V _H Supply Undervoltage Positive Going Threshold	V _{HUV+}		7.6	8.9	9.9	V
V _H Supply Undervoltage Negative Going Threshold	V _{HUV-}		6.7	8.1	9.5	V
V _L Supply Undervoltage Positive Going Threshold	V _{LUV+}		7.6	8.9	9.9	V
V _L Supply Undervoltage Negative Going Threshold	V _{LUV-}		6.7	8.1	9.5	V
Output High Short Circuit Pulsed Current	I _{O+}	V _{OUT} =0V, PW≤10μs	170	200		mA
Output Low Short Circuit Pulsed Current	I _{O-}	V _{OUT} =15V, PW≤10μs	340	400		mA

Block Diagram



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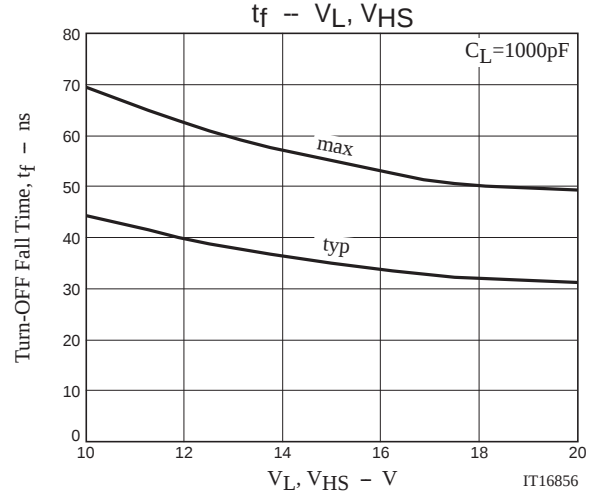
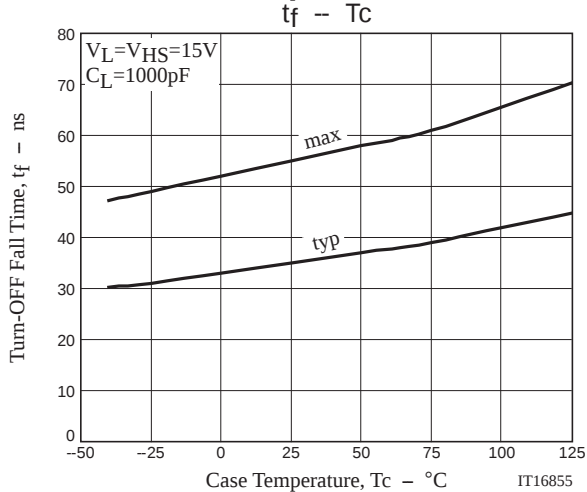
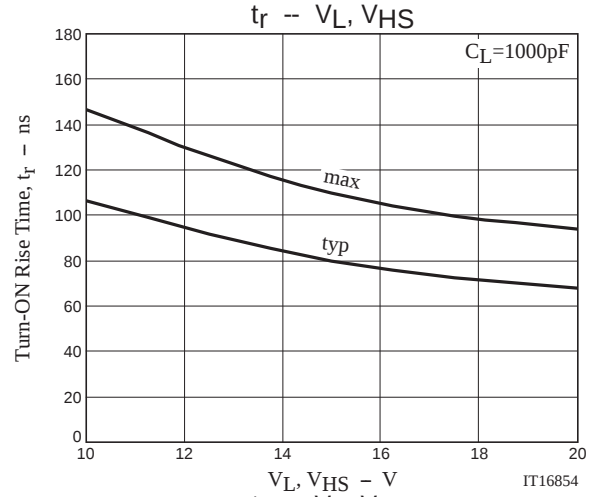
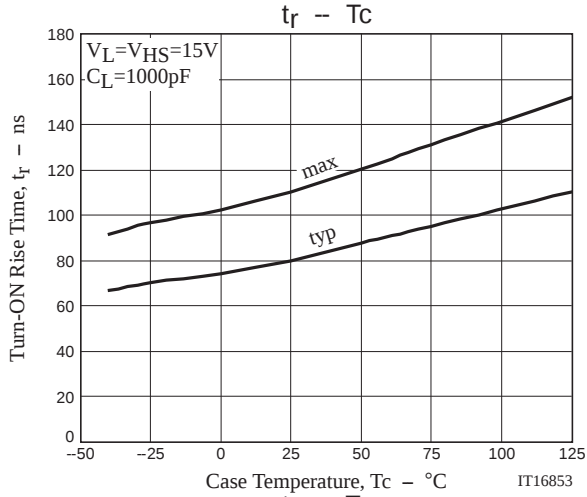
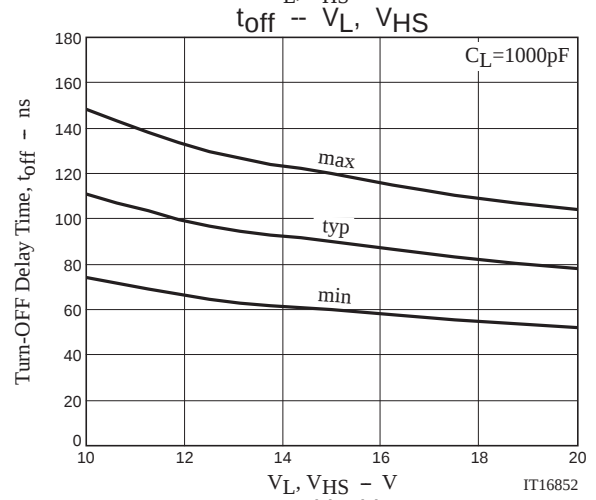
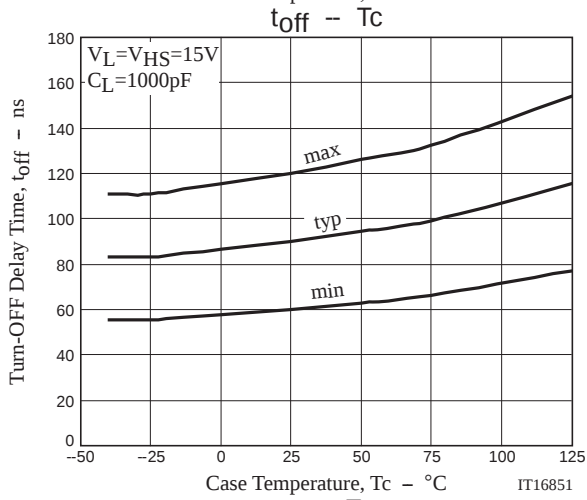
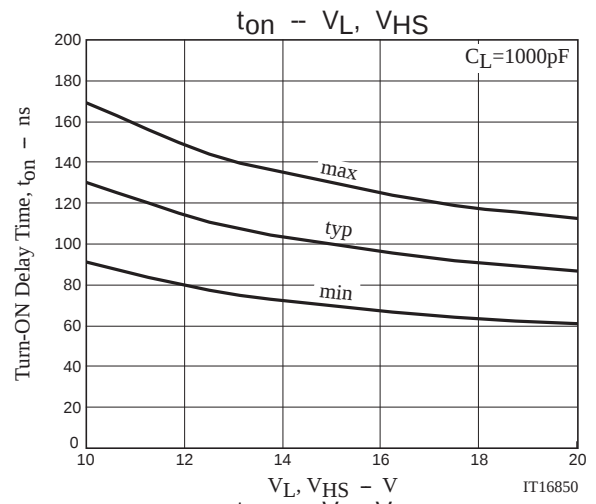
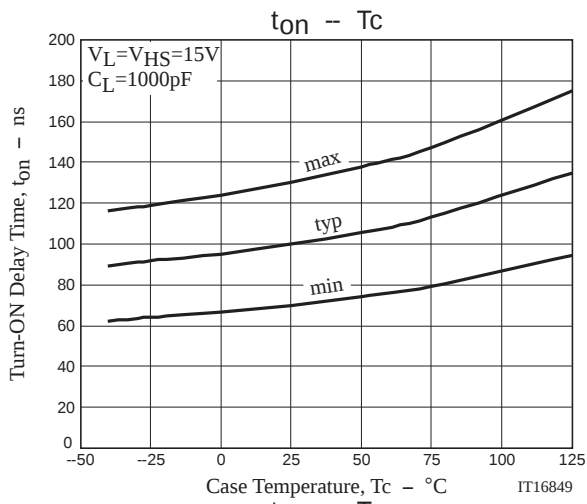
Switching Time Waveform Definition

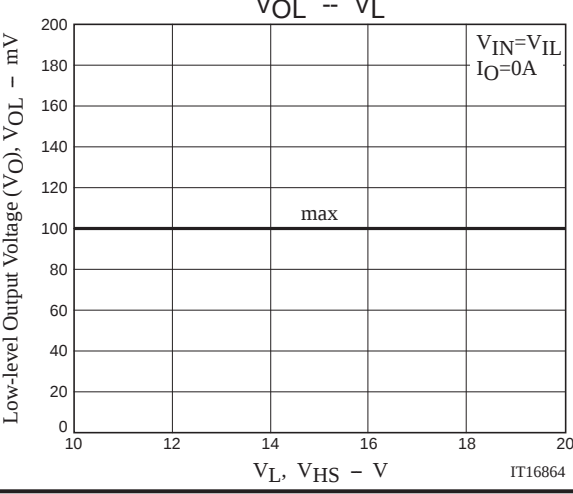
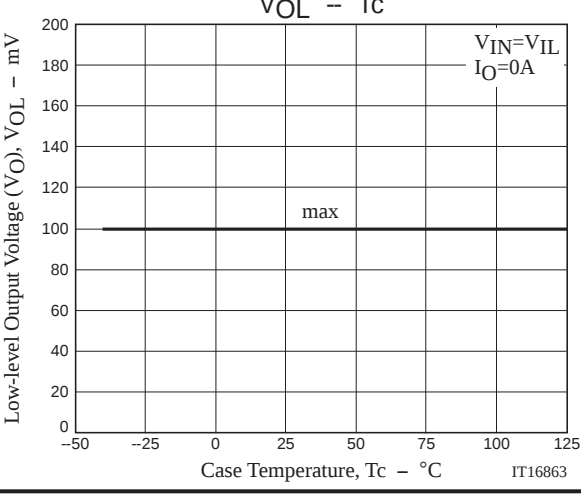
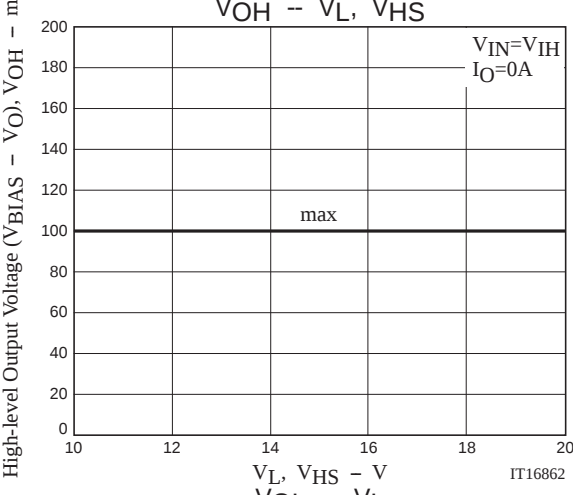
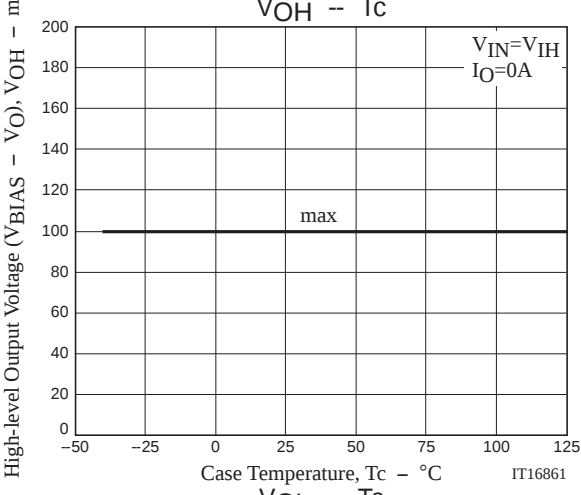
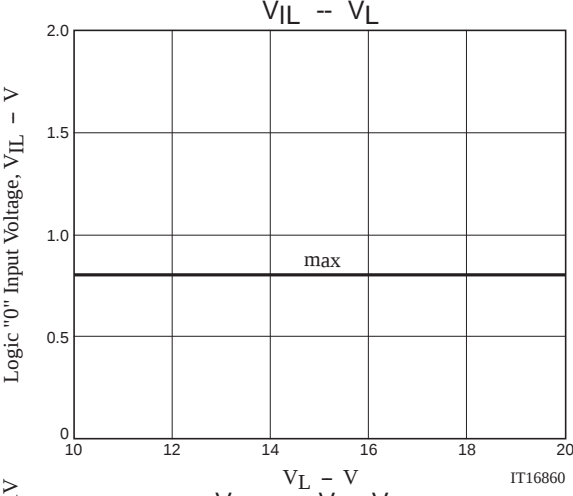
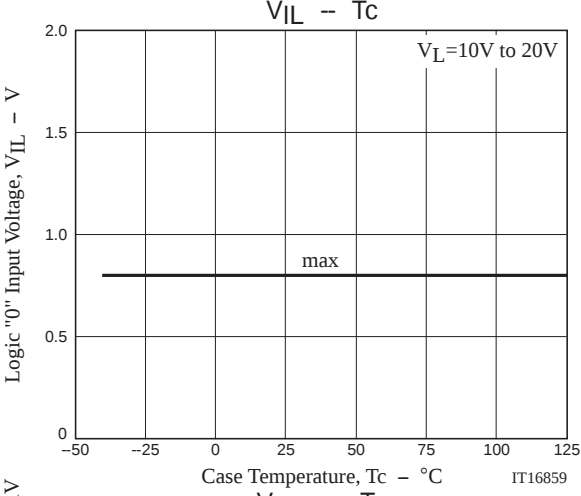
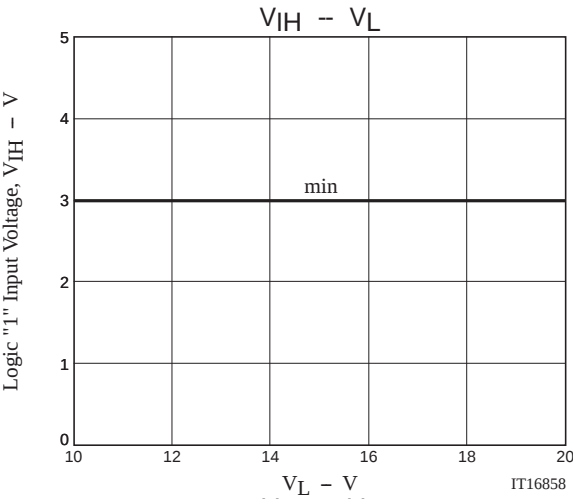
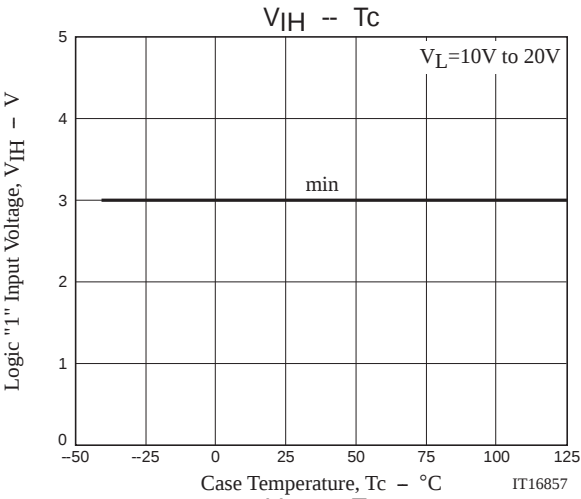


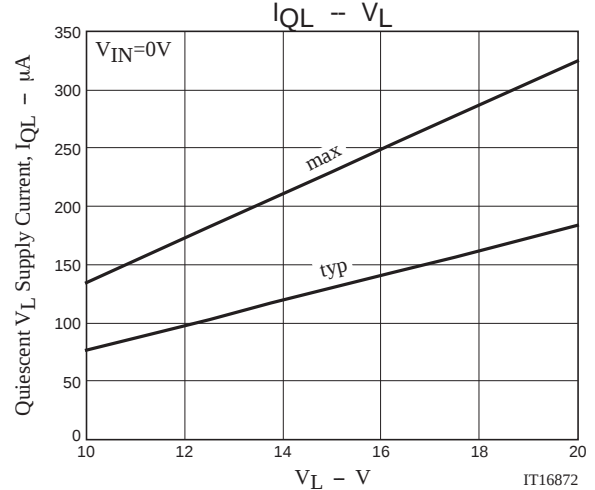
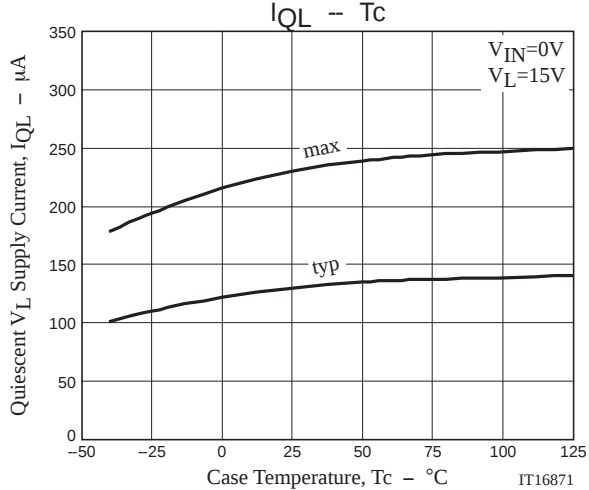
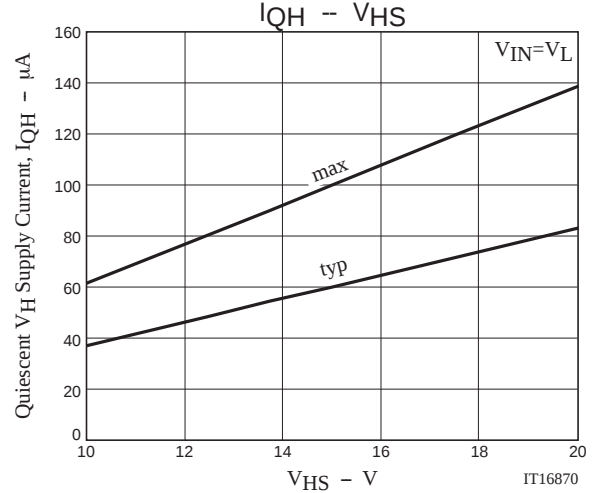
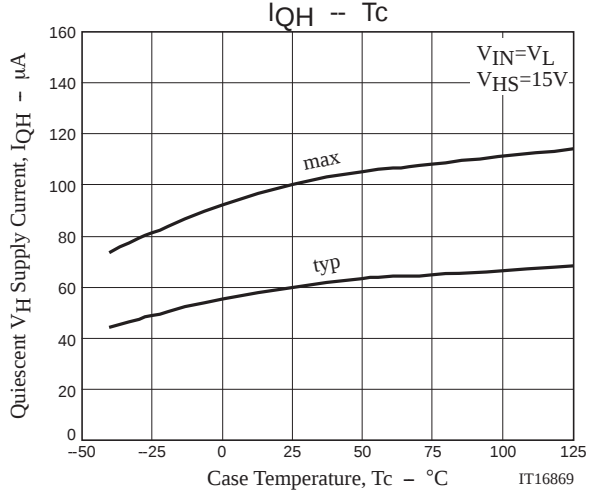
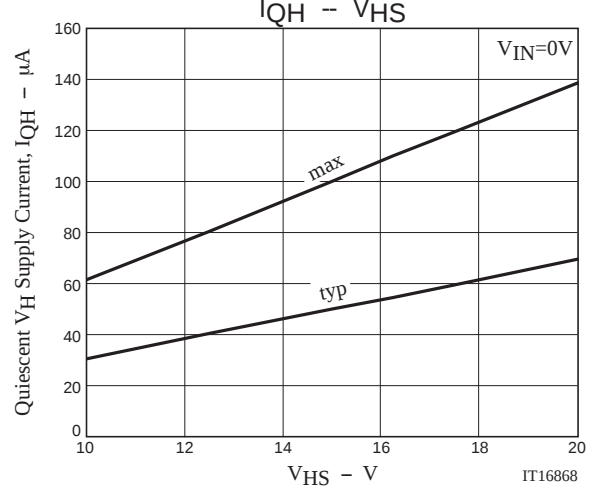
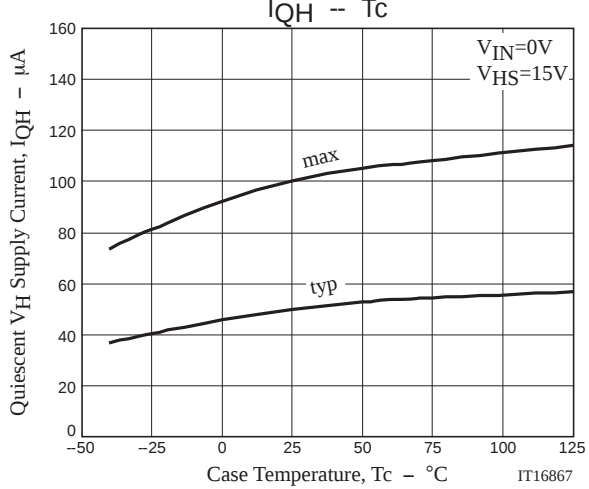
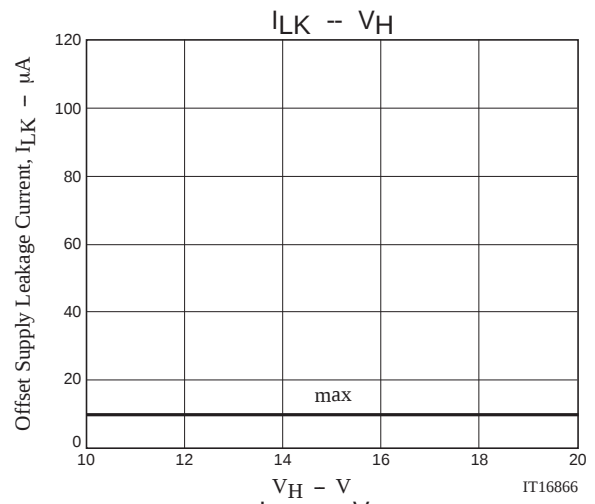
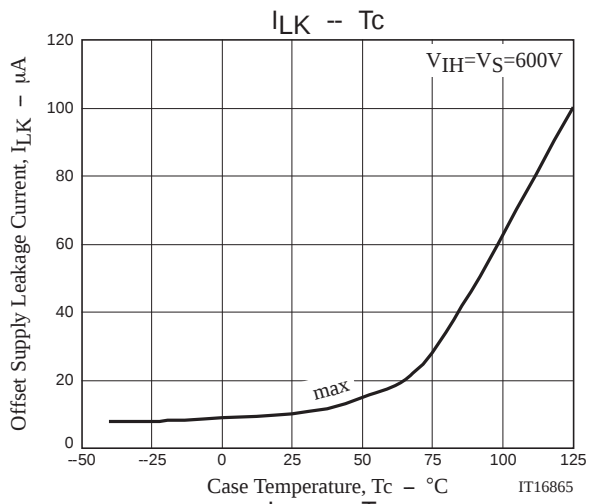
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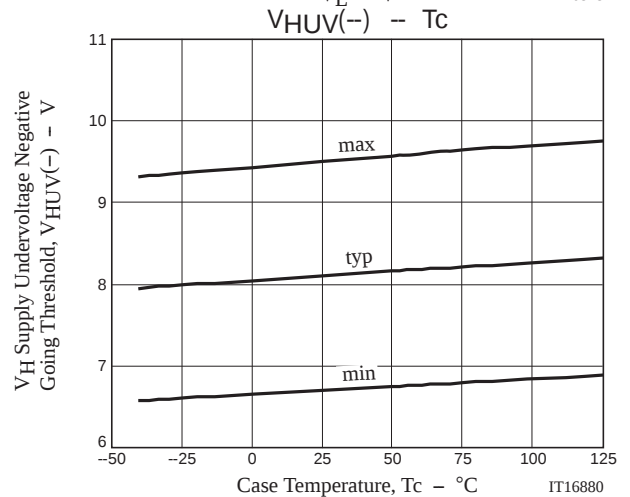
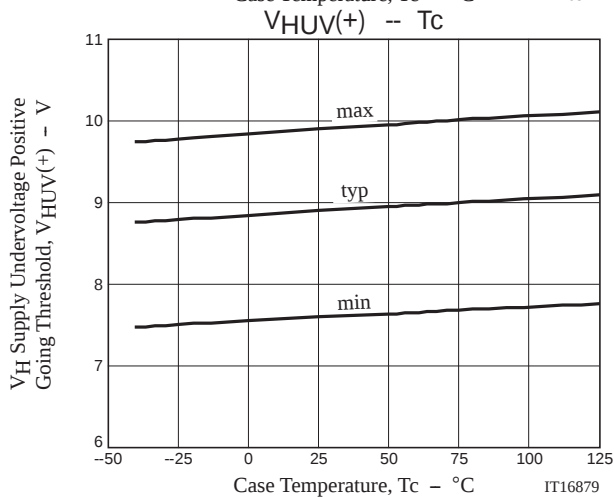
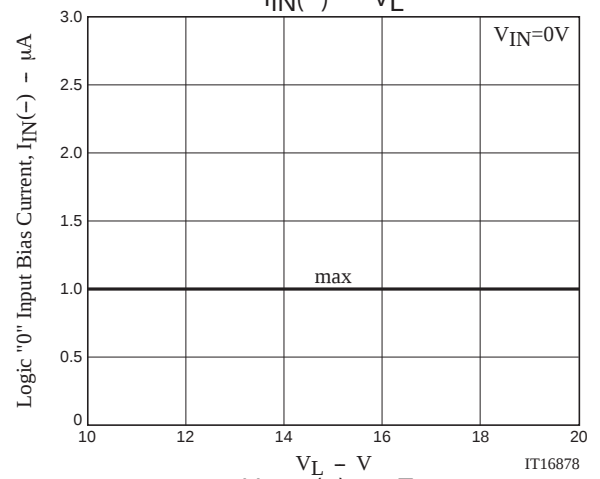
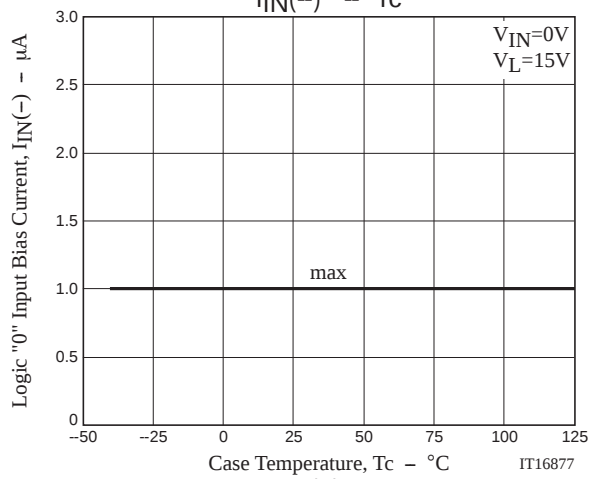
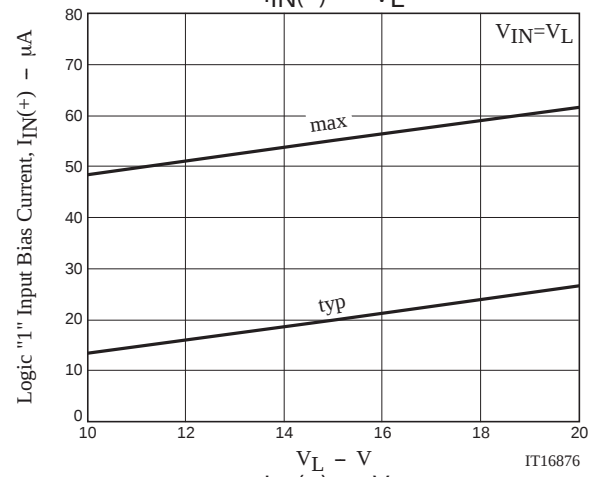
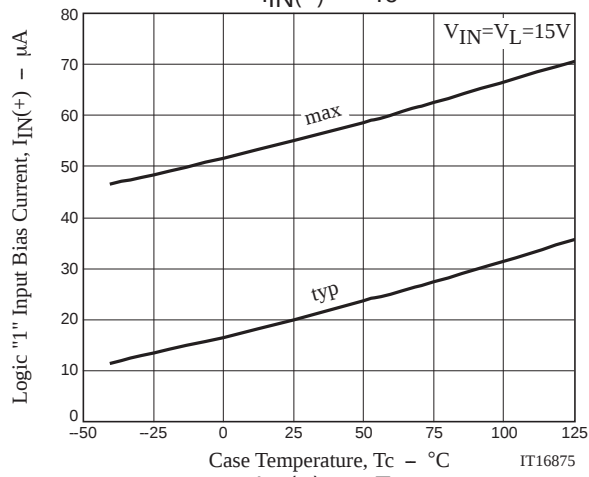
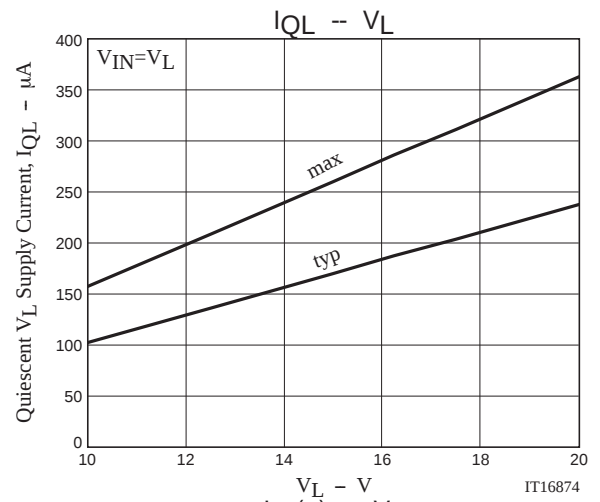
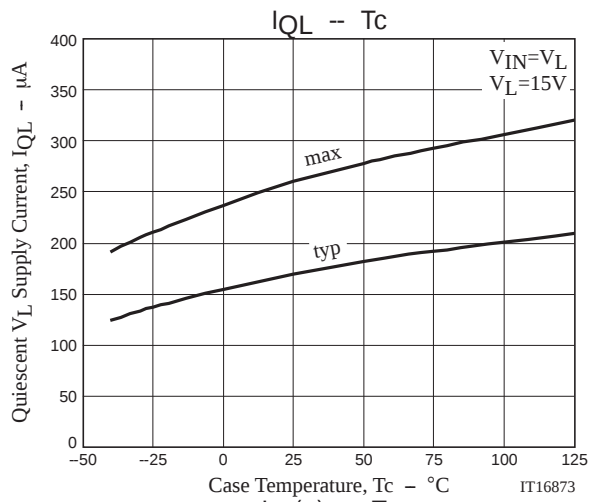


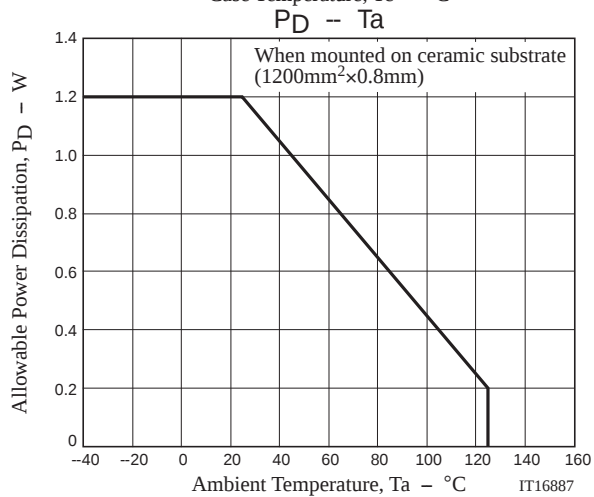
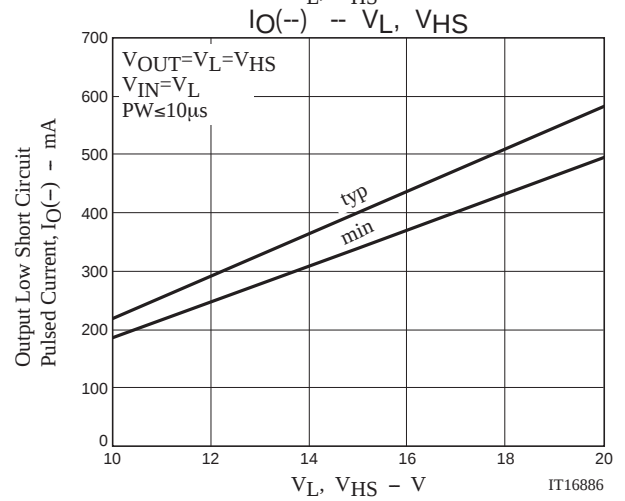
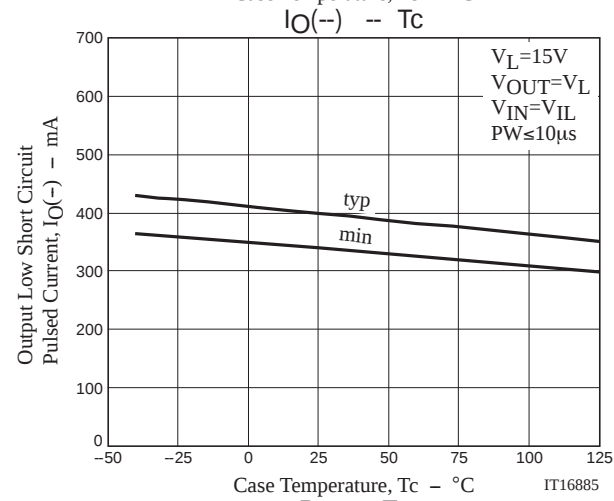
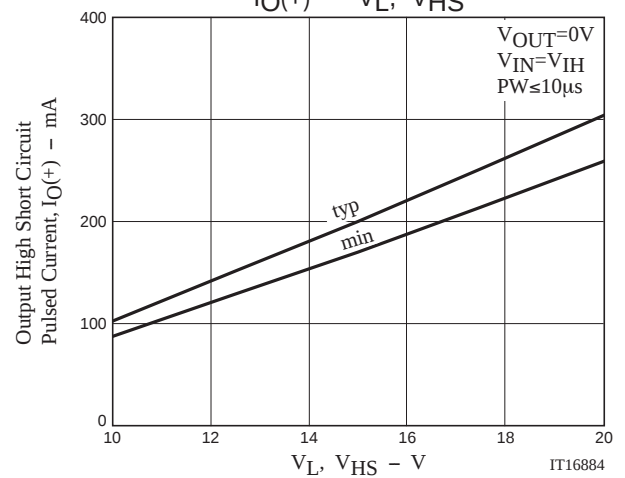
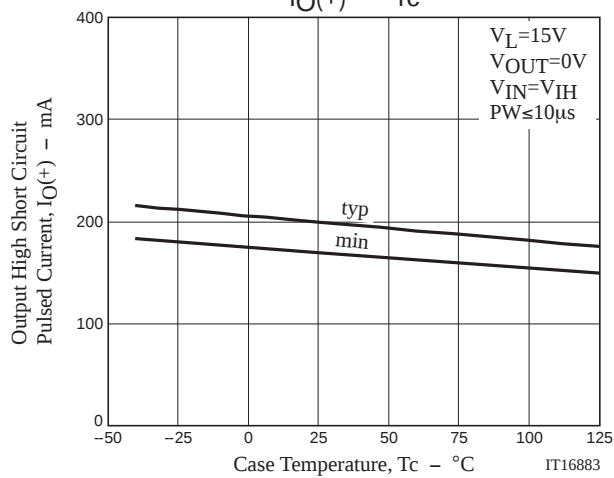
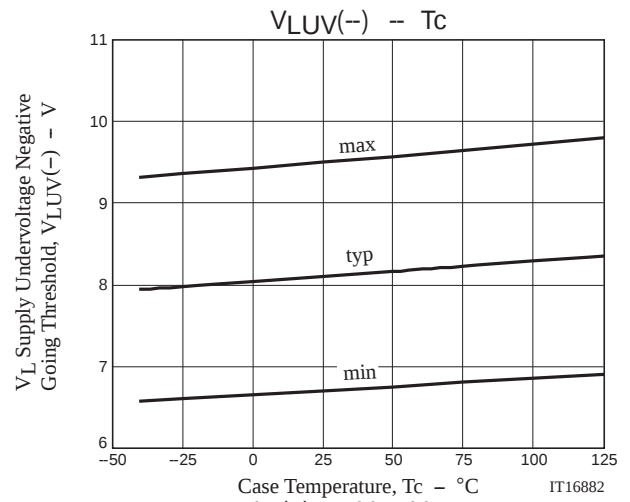
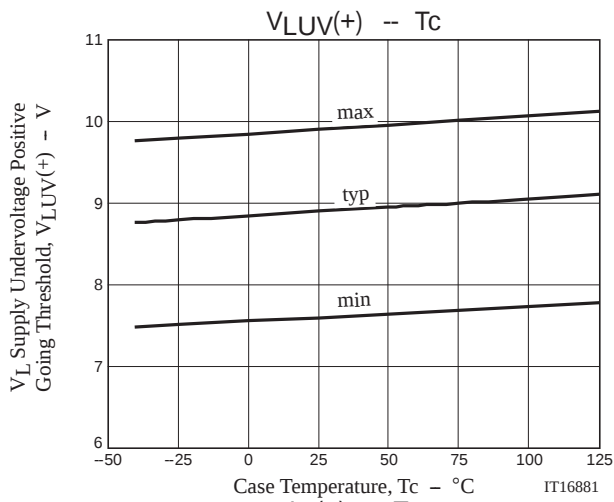
memo
Pb Free and Halogen Free











Taping Specification

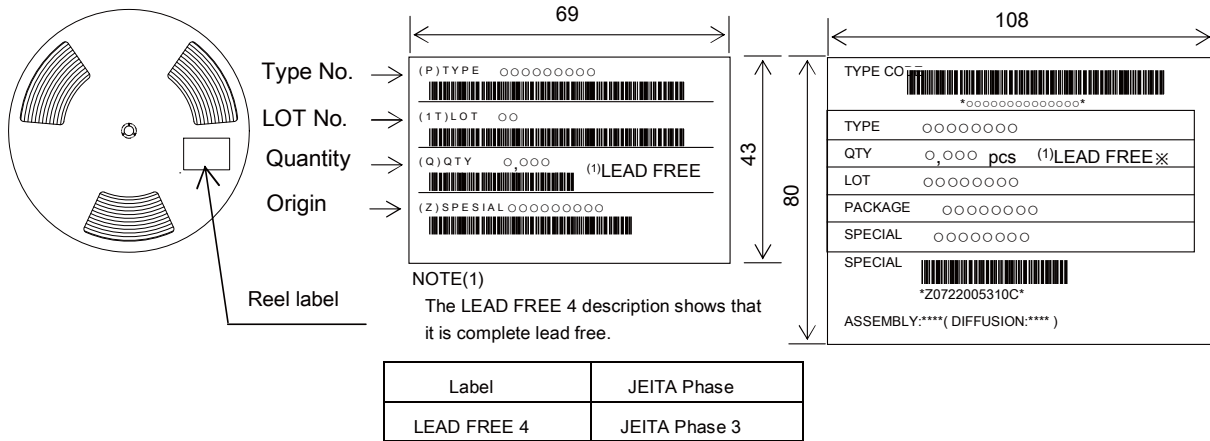
TND525SS-TL-2H

1. Packing Format

Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX W206-112	Outer BOX W207-124
SOIC8	B202-101	2,500	12,500	25,000	5 reels contained Dimensions :mm(external) 340×95×340	2 inner boxes contained Dimensions :mm(external) 360×210×375

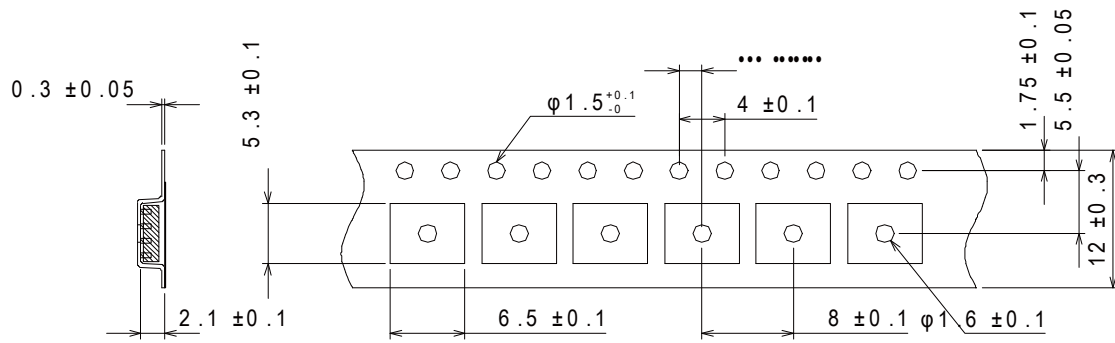
Packing methodReel label, Inner box label
(unit: mm)Outer box label

It is a label at the time of factory shipments.
The form of a label may change in physical distribution process.

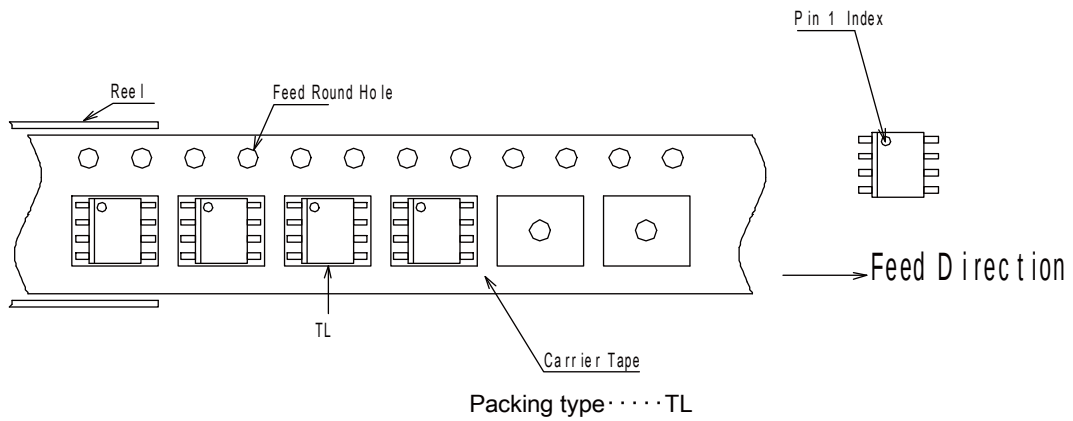


2. Taping configuration

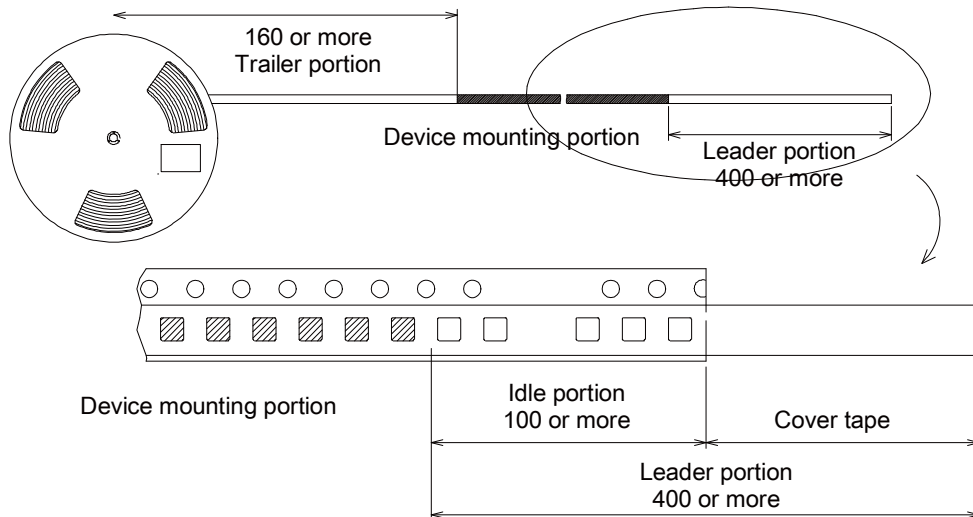
2-1. Carrier tape size (unit: mm)



2-2. Device placement direction

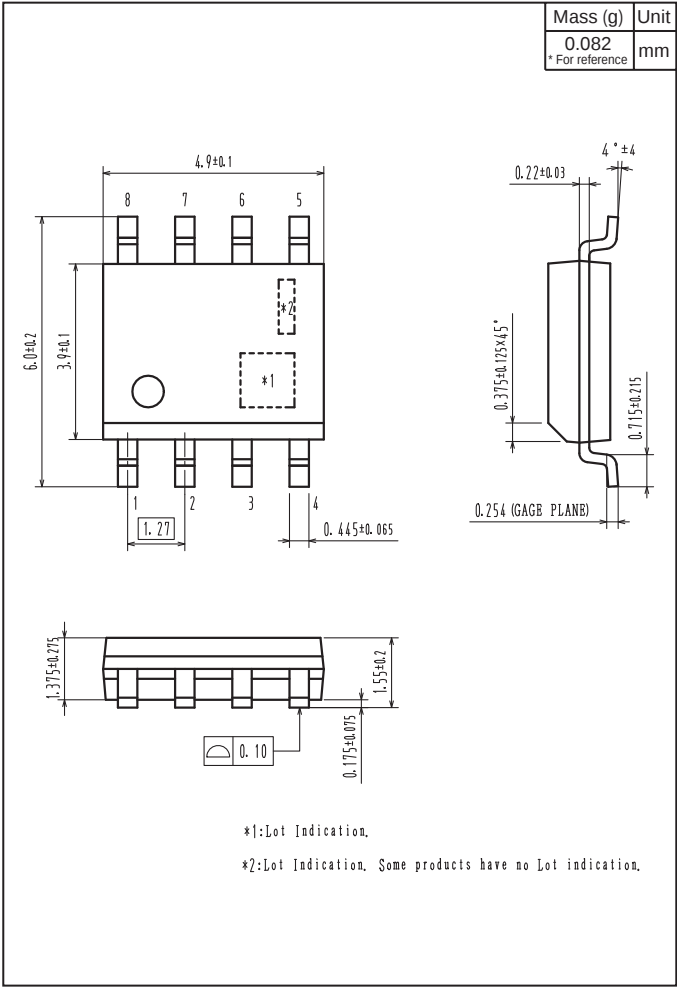


2-3. Leader portion and trailer portion (unit: mm)

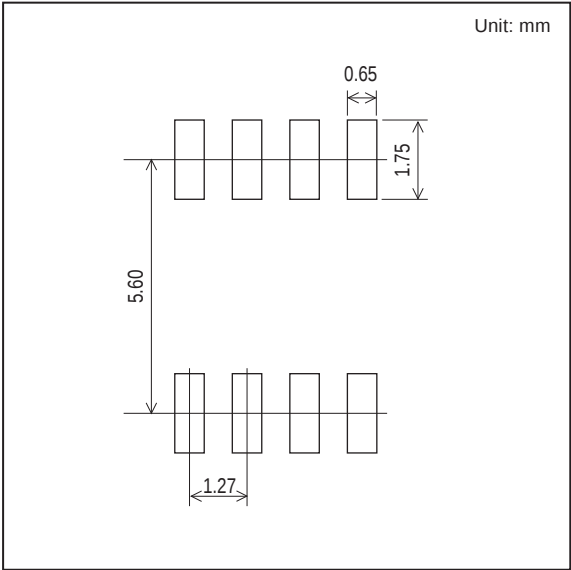


TND525SS

Outline Drawing
TND525SS-TL-2H



Land Pattern Example



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